

Features

- UltraBrightTM Performance
 - 3.8mW min (460nm) Deep Blue
 - 3.4mW min (470nm) Blue
 - 2.5mW min (505nm) Signal Green
 - 1.7mW min (527nm) Green
- Sorted to Wavelength and Power Bins
- Single Wire Bond Structure
- Class II ESD Rating

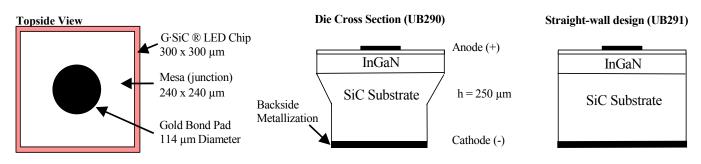
Description

Applications

- LED Video Displays
- White LEDs
- Automotive Dashboard Lighting
- Cellular Phone Backlighting
- Audio Product Display Lighting

Cree's UB[™] series of UltraBright[™] LEDs combine highly efficient InGaN materials with Cree's proprietary SiC® substrate to deliver excellent price performance for high intensity blue and green LEDs. UltraBright LED chips are available in a geometrically enhanced vertical structure or a straight-wall design for use in reflector-less applications such as ChipLEDs. Both require only a single wire bond connection. Sorted Die Kits provide die sheets conveniently sorted into wavelength and radiant flux bins. Cree's UB series chips are individually tested for conformity to optical and electrical specifications and the ability to withstand 1000V ESD. These LEDs are useful in a broad range of applications such as outdoor and indoor full motion LED video signs, transportation signaling and white LEDs, yet can also be used in high volume applications such as LCD backlighting. Cree's CB series chips are compatible with most radial and SMT LED assembly processes.

CXXX-UB29X-S0100 Chip Diagram





Maximum Ratings at $T_A = 25^{\circ}C^{\text{Notes }1\&3}$

	CXXX-UB29X-S0100
DC Forward Current	30 mA
Peak Forward Current (1/10 duty cycle @ 1kHz)	100 mA
LED Junction Temperature	125°C
Reverse Voltage	5 V
Operating Temperature Range	-20°C to +80°C
Storage Temperature Range	-30°C to +100°C
Electrostatic Discharge Threshold (HBM) Note 2	1000 V
Electrostatic Discharge Classification (MIL-STD-883E) ^{Note 2}	Class 2

Typical Electrical/Optical Characteristics at $T_A = 25^{\circ}C$, *If* = 20mA^{Note 3}

Part Number		Voltage	Reverse Current	Peak Wavelength	Halfwidth	Optical Rise Time	
Fait Nullibel	(V_{f}, V)		[I(Vr=5V), µA]	(λ_{p}, nm)	$(\lambda_{D_{i}} nm)$	(τ, ns)	
	Тур	Max	Max	Тур	Тур	Тур	
C460UB29X-S0100	3.5	3.9	10	458	26	30	
C470UB29X-S0100	3.5	3.9	10	468	26	30	
C505UB29X-S0100	3.5	3.9	10	502	30	30	
C527UB29X-S0100	3.5	3.9	10	518	36	30	

Mechanical Specifications Note 4	CXXX-UB29X-S0100	
Description	Dimension	Tolerance
P-N Junction Area (µm)	240 x 240	± 25
Top Area (µm)	300 x 300	± 25
UB290 Bottom Area (µm)	200 x 200	± 25
UB291 Bottom Area (µm)	300 x 300	± 25
Chip Thickness (µm)	250	± 25
Au Bond Pad Diameter (µm)	114	± 20
Au Bond Pad Thickness (µm)	1.2	± 0.5

Notes:

1) Maximum ratings are package dependent. The above ratings were determined using a T-1 3/4 package (with Hysol OS4000 epoxy) for characterization. Ratings for other packages may differ. The forward currents (DC and Peak) are not limited by the die but by the effect of the LED junction temperature on the package. The junction temperature limit of 125° C is a limit of the T-1 3/4 package; junction temperature should be characterized in a specific package to determine limitations. Assembly processing temperature must not exceed 350° C (< 15 minutes).

2) Product resistance to electrostatic discharge (ESD) according to the HBM is measured by simulating ESD using a rapid avalanche energy test (RAET). The RAET procedures are designed to approximate the maximum ESD ratings shown. The RAET procedure is performed on each die. The ESD classification of Class II is based on sample testing according to MIL-STD 883E.

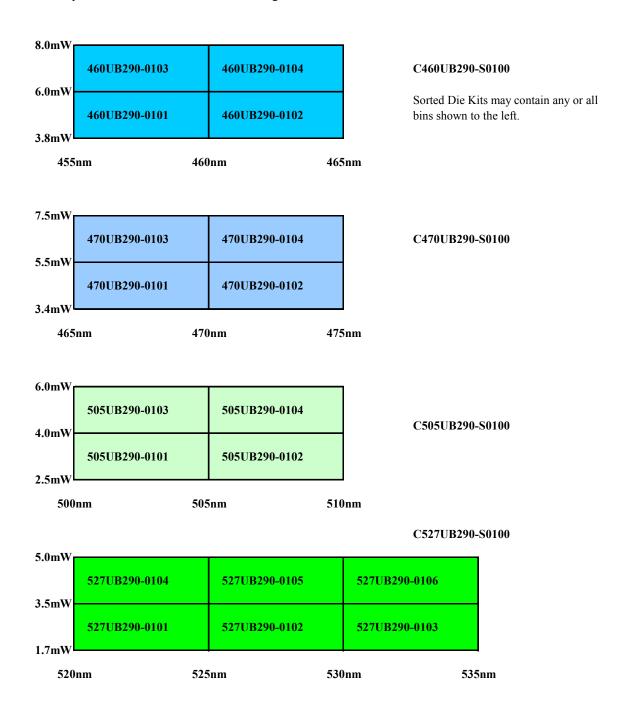
3) All Products conform to the listed minimum and maximum specifications for electrical and optical characteristics, when assembled and operated at 20 mA within the maximum ratings shown above. Efficiency decreases at higher currents. Typical values given are within the range of average values expected by the manufacturer in large quantities and are provided for information only. All measurements were made using lamps in T-1 3/4 packages (with Hysol OS4000 epoxy). Optical characteristics were measured in a Photoresearch Spectrascan Integrating Sphere. Illuminance E.

4) Specifications are subject to change without notice.



Standard Bins for UB290:

All LED chips are sorted onto die sheets according to the bins shown below.





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All LED chips are sorted onto die sheets according to the bins shown below.

